

Standard Recovery Diodes, (Stud Version), 380 A



DO-9 (DO-205AB)

FEATURES

- Wide current range
- High voltage ratings up to 3200 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- Compression bonded encapsulations
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	380 A
Package	DO-9 (DO-205AB)
Circuit configuration	Single

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VS-SD300N/R		UNITS
		16 to 20	25 to 32	
$I_{F(AV)}$		380	380	A
	T_C	100	70	°C
$I_{F(RMS)}$		595	425	A
I_{FSM}	50 Hz	6050	6050	
	60 Hz	6335	6335	
I^2t	50 Hz	183	183	kA ² s
	60 Hz	167	167	
V_{RRM}	Range	1600 to 2000	2500 to 3200	V
T_J		-40 to +180	-40 to +150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD300N/R	16	1600	1700	15
	20	2000	2100	
	25	2500	2600	
	28	2800	2900	
	32	3200	3300	

**FORWARD CONDUCTION**

PARAMETER	SYMBOL	TEST CONDITIONS			SD300N/R		UNITS
					16 to 20	25 to 32	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			380	270	A
					100	100	°C
					300	380	A
					125	70	°C
Maximum RMS forward current	I _{F(RMS)}	DC at T _C = 88 °C (02 to 24), T _C = 91 °C (25 to 32)			595	425	
Maximum peak, one-cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	6050		A
		t = 8.3 ms			6335		
		t = 10 ms	100 % V _{RRM} reapplied		5090		
		t = 8.3 ms			5330		
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		183		kA ² s
		t = 8.3 ms			167		
		t = 10 ms	100 % V _{RRM} reapplied		129		
		t = 8.3 ms			118		
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			1830		kA ² /s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			0.95		V
High level value of threshold voltage	V _{F(TO)2}	(I > π × I _{F(AV)}), T _J = T _J maximum			1.05		
Low level value of forward slope resistance	r _{f1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			0.75		mΩ
High level value of forward slope resistance	r _{f2}	(I > π × I _{F(AV)}), T _J = T _J maximum			0.66		
Maximum forward voltage drop	V _{FM}	I _{pk} = 1180 A, T _J = T _J maximum, t _p = 10 ms sinusoidal wave			1.83	1.83	V

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	SD300N/R		UNITS
			16 to 20	25 to 32	
Maximum junction operating temperature range	T _J		-40 to 180	-40 to 150	°C
Maximum storage temperature range	T _{Stg}		-55 to 200		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.11		K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat, and greased	0.04		
Maximum allowed mounting torque ± 10 %		Not-lubricated threads	27		Nm
Approximate weight			250		g
Case style		See dimensions (link at the end of datasheet)	DO-9 (DO-205AB)		

 ΔR_{thJC} CONDUCTION

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.019	0.013	$T_J = T_J$ maximum	K/W
120°	0.023	0.023		
90°	0.028	0.030		
60°	0.042	0.044		
30°	0.073	0.074		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

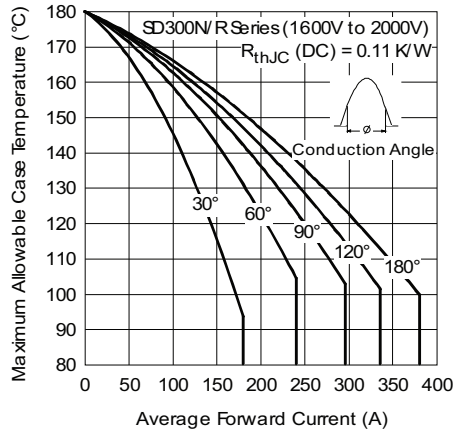


Fig. 1 - Current Ratings Characteristics

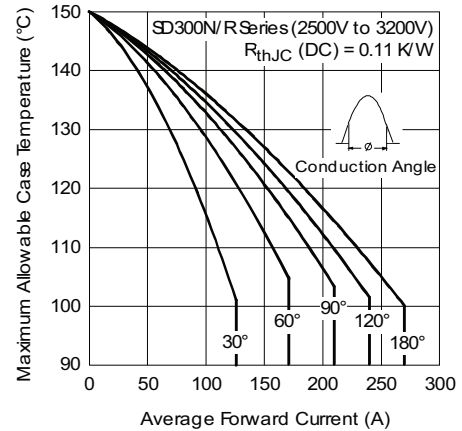


Fig. 3 - Current Ratings Characteristics

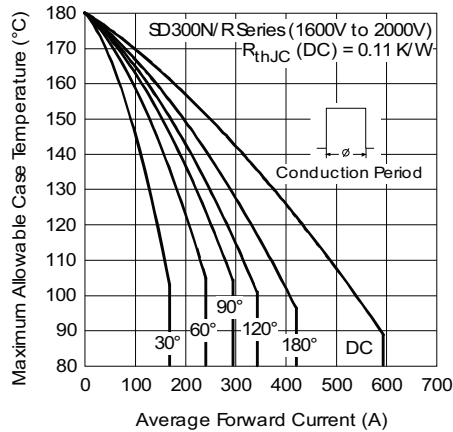


Fig. 2 - Current Ratings Characteristics

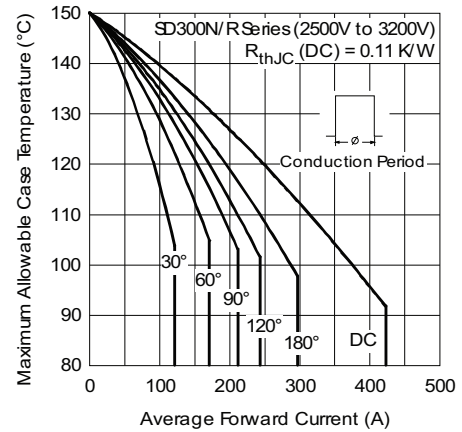


Fig. 4 - Current Ratings Characteristics

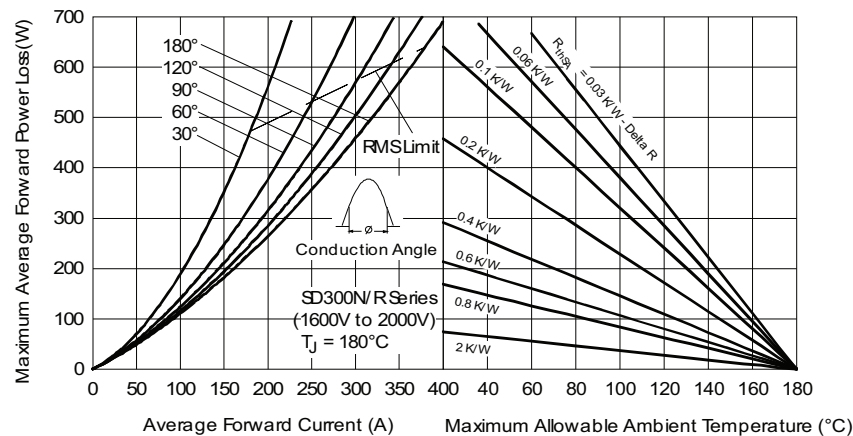


Fig. 5 - Forward Power Loss Characteristics

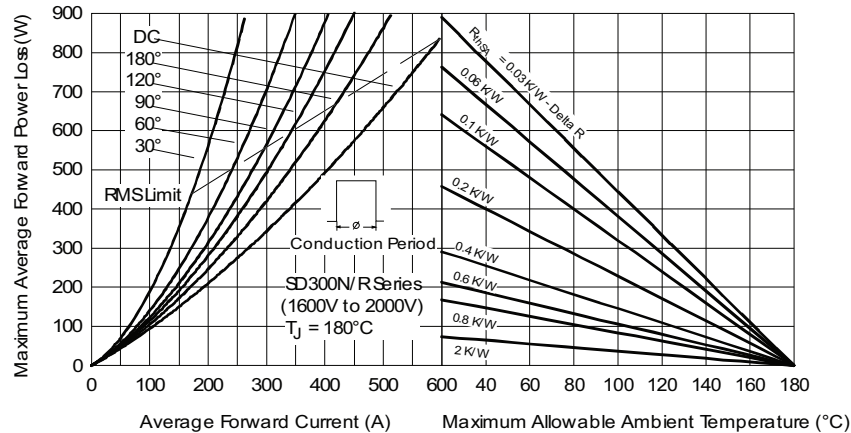


Fig. 6 - Forward Power Loss Characteristics

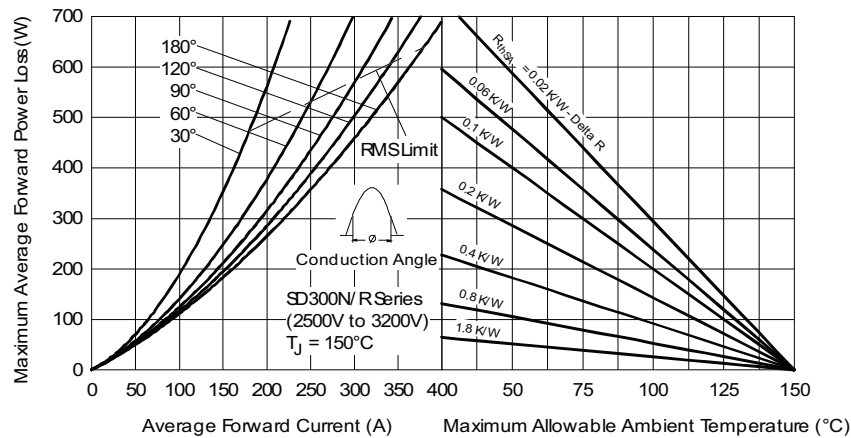


Fig. 7 - Forward Power Loss Characteristics

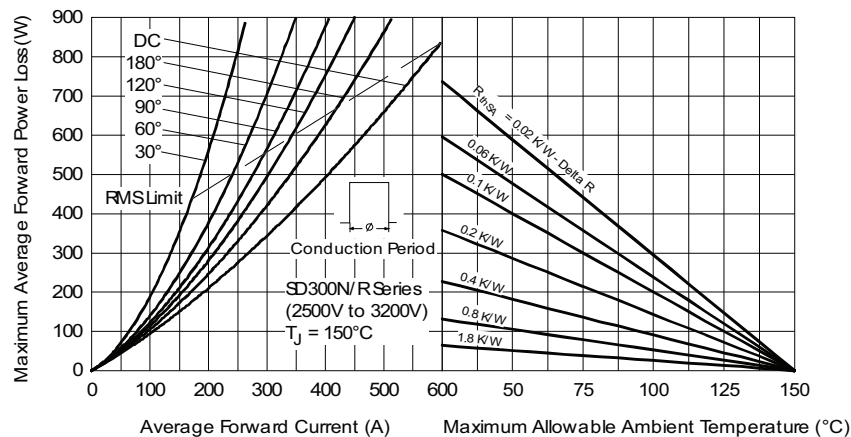


Fig. 8 - Forward Power Loss Characteristics

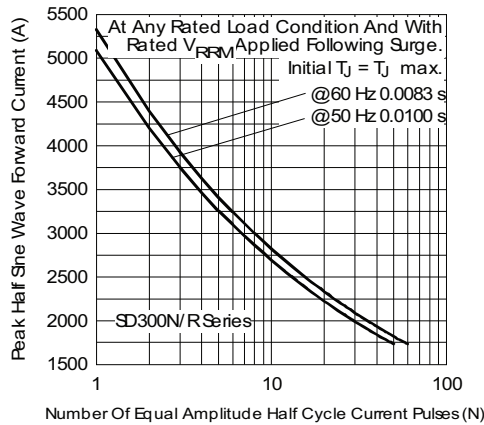


Fig. 9 - Maximum Non-Repetitive Surge Current

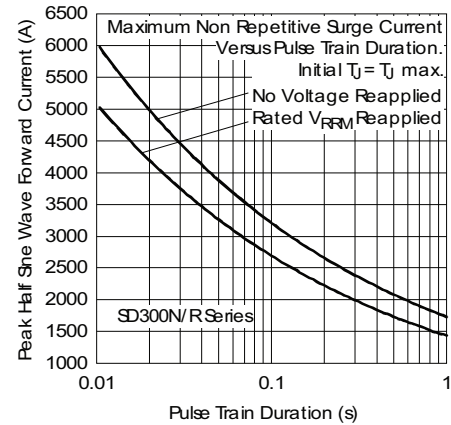


Fig. 10 - Maximum Non-Repetitive Surge Current

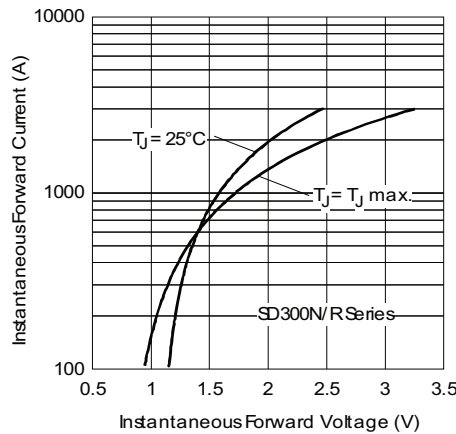
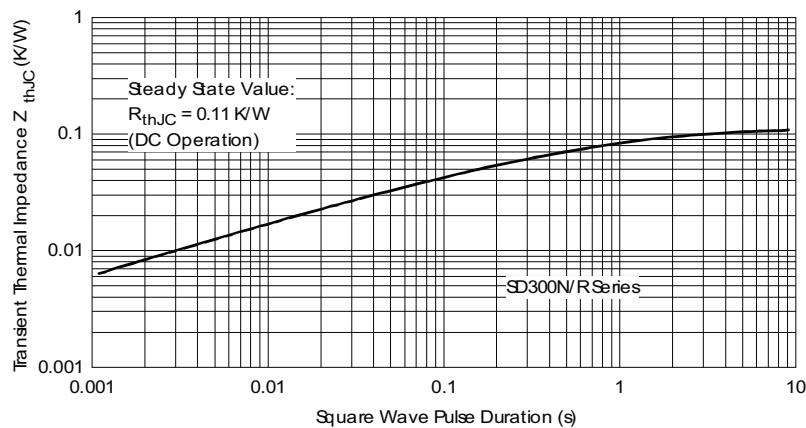


Fig. 11 - Forward Voltage Drop Characteristics


Fig. 12 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code	VS-	SD	30	0	N	32	P	C
	1	2	3	4	5	6	7	8
	1	2	3	4	5	6	7	8
	1 - Vishay semiconductors product 2 - Diode 3 - Essential part number 4 - 0 = standard recovery 5 - • N = stud normal polarity (cathode to stud) • R = stud reverse polarity (anode to stud) 6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table) 7 - P = stud base DO-9 (DO-205AB) 3/4" 16UNF-2A 8 - C = ceramic housing							

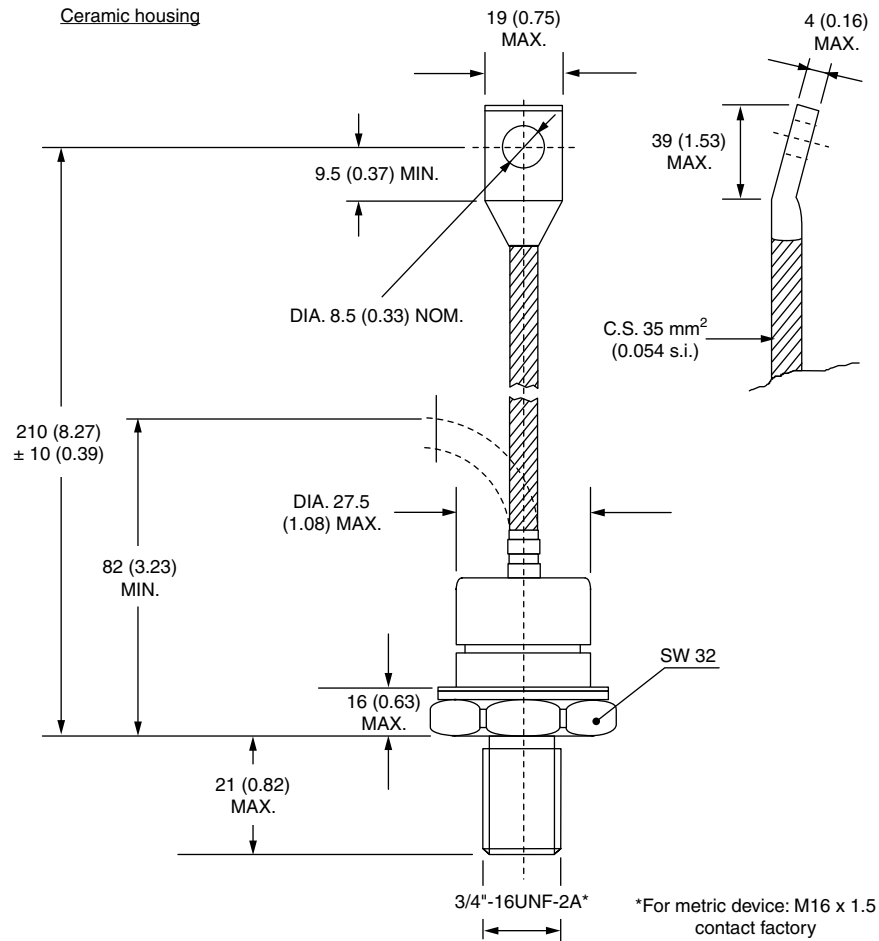
LINKS TO RELATED DOCUMENTS

Dimensions

www.vishay.com/doc?95301

DO-205AB (DO-9)

DIMENSIONS in millimeters (inches)





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